**Vishay Semiconductors** 

- 175 °C operating junction temperature
- Low leakage current

**FEATURES** 

- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>BMS</sub>)
- True 2 pin package
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### DESCRIPTION

Ultralow V<sub>F</sub>, soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

### **APPLICATIONS**

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

| ABSOLUTE MAXIMUM RATINGS                    |                                   |                         |             |       |
|---|-----------------------------------|-------------------------|-------------|-------|
| PARAMETER                                   | SYMBOL                            | TEST CONDITIONS         | VALUES      | UNITS |
| Peak repetitive reverse voltage             | V <sub>RRM</sub>                  |                         | 500         | V     |
| Average rectified forward current in DC     | I <sub>F(AV)</sub>                | T <sub>C</sub> = 124 °C | 8           | ٨     |
| Non-repetitive peak surge current           | I <sub>FSM</sub>                  | $T_J = 25 \ ^{\circ}C$  | 110         | A     |
| Operating junction and storage temperatures | T <sub>J</sub> , T <sub>Stg</sub> |                         | -65 to +175 | °C    |

| <b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                                     |   |      |       |      |       |  |
|--|-------------------------------------|---|------|-------|------|-------|--|
| PARAMETER  | SYMBOL                              | TEST CONDITIONS                                 | MIN. | TYP.  | MAX. | UNITS |  |
| Breakdown voltage,<br>blocking voltage   | V <sub>BR</sub> ,<br>V <sub>R</sub> | Ι <sub>R</sub> = 100 μΑ                         | 500  | -     | -    |       |  |
| Forward voltage  | V                                   | I <sub>F</sub> = 8 A                            | -    | 1.05  | 1.25 | V     |  |
| orward voltage V <sub>F</sub>  |                                     | I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C   | -    | 0.9   | 1.03 |       |  |
|  | 1                                   | $V_{R} = V_{R}$ rated                           | -    | 0.005 | 9    |       |  |
| Reverse leakage current  | I <sub>R</sub>                      | $T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$ | -    | 5     | 50   | μA    |  |
| Junction capacitance   | CT                                  | V <sub>R</sub> = 500 V                          | -    | 6     | -    | pF    |  |
| Series inductance  | Ls                                  | Measured lead to lead 5 mm from package body    | -    | 8     | -    | nH    |  |

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## Ultrafast Rectifier, 8 A FRED Pt<sup>®</sup>



www.vishay.com

2L TO-220 FullPAK

| PRIMARY CHARACTERISTICS          |                   |  |  |  |  |
|----------------------------------|-------------------|--|--|--|--|
| I <sub>F(AV)</sub>               | 8 A               |  |  |  |  |
| VR                               | 500 V             |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 0.9 V             |  |  |  |  |
| t <sub>rr</sub> (typ.)           | 28 ns             |  |  |  |  |
| T <sub>J</sub> max.              | 175 °C            |  |  |  |  |
| Package                          | 2L TO-220 FullPAK |  |  |  |  |
| Circuit configuration            | Single            |  |  |  |  |



# VS-ETU0805FP-M3



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## Vishay Semiconductors

| <b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified) |                         |   |   |      |      |       |    |  |
|---|-------------------------|---|---|------|------|-------|----|--|
| PARAMETER   | SYMBOL                  | TEST CO   | MIN.  | TYP. | MAX. | UNITS |    |  |
|   |                         |   | $I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$ |      | 28   | -     |    |  |
| Reverse recovery time t <sub>rr</sub>   | +                       | $I_F = 8 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$ |   | -    | 54   | -     | ns |  |
|   | T <sub>J</sub> = 25 °C  |   | -   | 50   | -    |       |    |  |
|   |                         | T <sub>J</sub> = 125 °C   |   | -    | 90   | -     |    |  |
| Peak recovery current   |                         | T <sub>J</sub> = 25 °C  | I <sub>F</sub> = 8 A,<br>dI <sub>F</sub> /dt = 200 A/μs,  | -    | 7.0  | -     | А  |  |
| Peak recovery current I <sub>RRM</sub>  | T <sub>J</sub> = 125 °C | $V_{\rm B} = 200 \text{ V},$  |   | -    | A    |       |    |  |
|   | 0                       | T <sub>J</sub> = 25 °C  |   | -    | 180  | -     | -0 |  |
| Reverse recovery charge Q <sub>rr</sub>   |                         | T <sub>J</sub> = 125 °C   |   | -    | 450  | -     | nC |  |

| THERMAL - MECHANICAL SPECIFICATIONS             |                                   |  |              |       |            |                        |  |
|---|-----------------------------------|--|--------------|-------|------------|------------------------|--|
| PARAMETER                                       | SYMBOL                            | TEST CONDITIONS                            | MIN.         | TYP.  | MAX.       | UNITS                  |  |
| Maximum junction and storage temperature range  | T <sub>J</sub> , T <sub>Stg</sub> |  | -65          | -     | 175        | °C                     |  |
| Thermal resistance,<br>junction-to-case         | R <sub>thJC</sub>                 |  | -            | 4.4   | 5.5        |                        |  |
| Thermal resistance,<br>junction-to-ambient      | R <sub>thJA</sub>                 | Typical socket mount                       | -            | -     | 50         | °C/W                   |  |
| Typical thermal resistance,<br>case-to-heatsink | R <sub>thCS</sub>                 | Mounting surface, flat, smooth and greased | -            | 0.5   | -          |                        |  |
| Weight  |                                   |  | -            | 2.0   | -          | g                      |  |
| weight  |                                   |  | -            | 0.007 | -          | oz.                    |  |
| Mounting torque                                 |                                   |  | 6.0<br>(5.0) | -     | 12<br>(10) | kgf · cm<br>(lbf · in) |  |
| Marking device                                  |                                   | Case style 2L TO-220 FullPAK               |              | ETU0  | 805FP      |                        |  |



## VS-ETU0805FP-M3

### **Vishay Semiconductors**

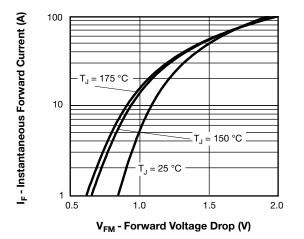


Fig. 1 - Typical Forward Voltage Drop Characteristics

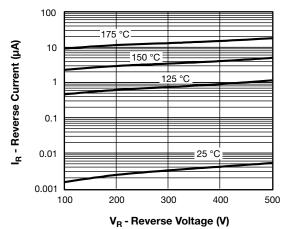


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

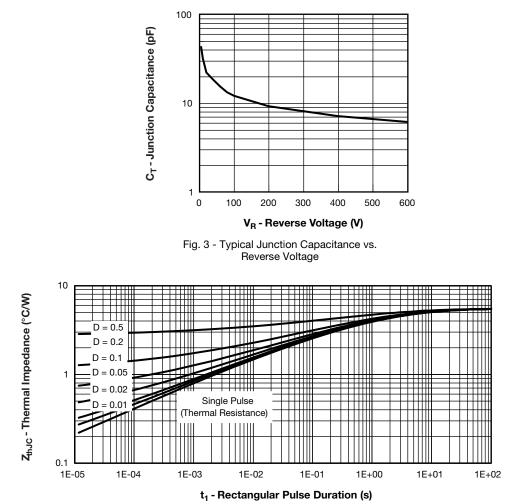


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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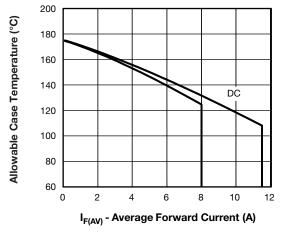
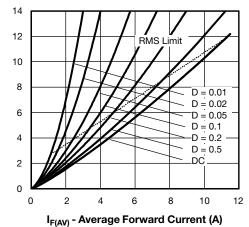


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current



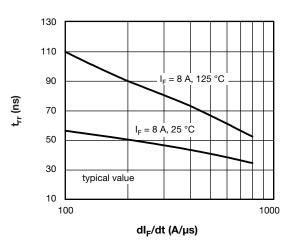
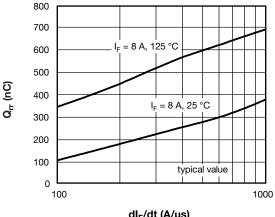


Fig. 7 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt



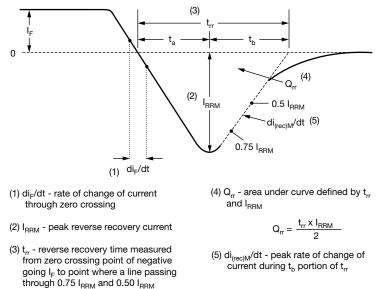


Fig. 9 - Reverse Recovery Waveform and Definitions

extrapolated to zero current.

dl<sub>F</sub>/dt (A/µs) Fig. 6 - Forward Power Loss Characteristics Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

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Average Power Loss (W)

VS-ETU0805FP-M3

### **Vishay Semiconductors**

### Vishay Semiconductors

### **ORDERING INFORMATION TABLE**

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| Device code | VS- | Е      | т        | U          | 08       | 05     | FP       | -M3      |
|-------------|-----|--------|----------|------------|----------|--------|----------|----------|
|             |     |        |          |            |          |        |          |          |
|             | (1) | (2)    | (3)      | (4)        | (5)      | (6)    | (7)      | (8)      |
|             | 1 · | - Visł | nay Sem  | nicondu    | ctors pr | oduct  |          |          |
|             | 2 - | - Circ | cuit con | figuratio  | n:       |        |          |          |
|             |     | E =    | single   |            |          |        |          |          |
|             | 3 - | - T=   | TO-220   | )          |          |        |          |          |
|             | 4   | - U =  | hyperfa  | ast reco   | very tim | е      |          |          |
|             | 5   | - Cur  | rent coo | de: 08 =   | 8 A      |        |          |          |
|             | 6   | - Volt | tage coo | de: 05 =   | 500 V    |        |          |          |
|             | 7 - | FP :   | = 2L TO  | -220 Fu    | IIPAK    |        |          |          |
|             | 8 - | - Env  | rironmer | ntal digit | :        |        |          |          |
|             |     | -M3    | 3 = halo | gen-free   | e, RoHS  | compli | ant, and | d termin |

| ORDERING INFORMATION (Example) |  |      |                         |  |  |  |  |
|--------------------------------|--|------|-------------------------|--|--|--|--|
| PREFERRED P/N                  | QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION |      |                         |  |  |  |  |
| VS-ETU0805FP-M3                | 50   | 1000 | Antistatic plastic tube |  |  |  |  |

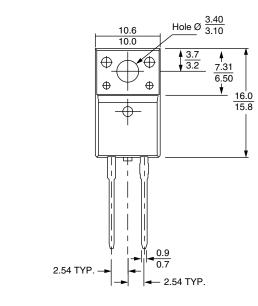
| LINKS TO RELATED DOCUMENTS                 |                          |  |  |  |  |
|--|--------------------------|--|--|--|--|
| Dimensions <u>www.vishay.com/doc?96157</u> |                          |  |  |  |  |
| Part marking information                   | www.vishay.com/doc?95392 |  |  |  |  |

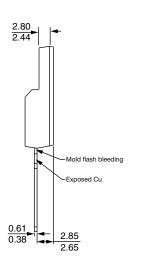


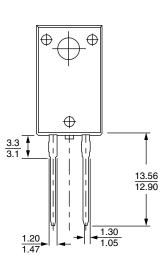
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# 2L TO-220 FullPAK

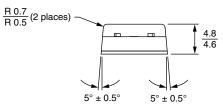
#### **DIMENSIONS** in millimeters







Bottom view





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